-5V Differential ECL to TTL Translator

The MC10ELT/100ELT25 is a differential ECL to TTL translator. Because ECL levels are used, a +5 V, -5.2 V (or -4.5 V) and ground are required. The small outline 8-lead package and the single gate of the ELT25 makes it ideal for those applications where space, performance and low power are at a premium.

The V_{BB} pin, an internally generated voltage supply, is available to this device only. For single-ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a 0.01 μF capacitor and limit current sourcing or sinking to 0.5 mA. When not used, V_{BB} should be left open.

The 100 Series contains temperature compensation.

- 2.6 ns Typical Propagation Delay
- 100 MHz F_{MAX} CLK
- 24 mA TTL Outputs
- Flow Through Pinouts
- ESD Protection: >1 KV HBM, > 400 V MM
- Operating Range: V_{CC} = 4.5 V to 5.5 V with GND= 0 V; V_{EE} = -4.2 V to -5.7 V with GND= 0 V
- Internal Input Pulldown Resistors
- Q Output will default HIGH with inputs open or < 1.3 V
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Level 1
 For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL-94 code V-0 @ 1/8", Oxygen Index 28 to 34
- Transistor Count = 38 devices

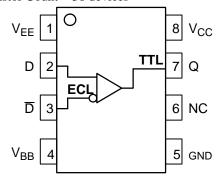


Figure 1. 8-Lead Pinout and Logic Diagram (Top View)

PIN DESCRIPTION

PIN	FUNCTION
D, D Q V _{BB} V _{CC} VEE GND NC	ECL Differential Inputs TTL Output Reference Voltage Output Positive Supply Negative Supply Ground No Connect



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MARKING DIAGRAMS*



SO-8 D SUFFIX CASE 751







CASE 948R





 $\begin{array}{lll} H = MC10 & L = Wafer \ Lot \\ K = MC100 & Y = Year \\ A = Assembly \ Location & W = Work \ Week \end{array}$

ORDERING INFORMATION

Device	Package	Shipping
MC10ELT25D	SO-8	98 Units/Rail
MC10ELT25DR2	SO-8	2500 Tape & Reel
MC100ELT25D	SO-8	98 Units/Rail
MC100ELT25DR2	SO-8	2500 Tape & Reel
MC10ELT25DT	TSSOP-8	98 Units/Rail
MC10ELT25DTR2	TSSOP-8	2500 Tape & Reel
MC100ELT25DT	TSSOP-8	98 Units/Rail
MC100ELT25DTR2	TSSOP-8	2500 Tape & Reel

^{*}For additional information, see Application Note AND8002/D

MAXIMUM RATINGS (Note 1)

Symbol	Parameter	Condition 1	Condition 2	Rating	Units
V _{CC}	Positive Power Supply	GND = 0 V	V _{EE} = -5.0 V	7	V
V _{EE}	Negative Power Supply	GND = 0 V	V _{CC} = +5.0 V	-8	٧
V _{IN}	Input Voltage	GND = 0 V		0 to V _{EE}	٧
I _{BB}	V _{BB} Sink/Source			± 0.5	mA
TA	Operating Temperature Range			-40 to +85	°C
T _{stg}	Storage Temperature Range			-65 to +150	°C
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 SOIC 8 SOIC	190 130	°C/W
θ_{JC}	Thermal Resistance (Junction to Case)	std bd	8 SOIC	41 to 44	°C/W
θ_{JA}	Thermal Resistance (Junction to Ambient)	0 LFPM 500 LFPM	8 TSSOP 8 TSSOP	185 140	°C/W
$\theta_{\sf JC}$	Thermal Resistance (Junction to Case)	std bd	8 TSSOP	41 to 44 ± 5%	°C/W
T _{sol}	Wave Solder	<2 to 3 sec @ 248°C		265	°C

^{1.} Maximum Ratings are those values beyond which device damage may occur.

10ELT SERIES NECL DC CHARACTERISTICS V_{CC} = 5.0 V; V_{EE} = -5.0 V; GND= 0 V (Note 2)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V _{IH}	Input HIGH Voltage (Single Ended)	-1230		-890	-1130		-810	-1060		-720	mV
V_{IL}	Input LOW Voltage (Single Ended)	-1950		-1500	-1950		-1480	-1950		-1445	mV
V_{BB}	Output Voltage Reference	-1.43		-1.30	-1.35		-1.25	-1.31		-1.19	V
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 3)	-2.8		0.0	-2.8		0.0	-2.8		0.0	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.3			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 2. Input parameters vary 1:1 with GND. V_{EE} can vary +0.06 V / -0.5 V. 3. V_{IHCMR} min varies 1:1 with V_{EE} , V_{IHCMR} max varies 1:1 with GND.

100ELT SERIES NECL DC CHARACTERISTICS V_{CC} = 5.0 V; V_{EE} = -5.0 V; GND= 0 V (Note 4)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
V _{IH}	Input HIGH Voltage (Single Ended)	-1165		-880	-1165		-880	-1165		-880	mV
V _{IL}	Input LOW Voltage (Single Ended)	-1810		-1475	-1810		-1475	-1810		-1475	mV
V_{BB}	Output Voltage Reference	-1.38		-1.26	-1.38		-1.26	-1.38		-1.26	V
V _{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 5)	-2.8		0.0	-2.8		0.0	-2.8		0.0	V
I _{IH}	Input HIGH Current			150			150			150	μΑ
I _{IL}	Input LOW Current	0.5			0.5			0.5			μΑ

NOTE: Devices are designed to meet the DC specifications shown in the above table, after thermal equilibrium has been established. The circuit is in a test socket or mounted on a printed circuit board and transverse air flow greater than 500 lfpm is maintained.

- 4. Input parameters vary 1:1 with GND. V_{EE} can vary +0.8 V / -0.5 V. 5. V_{IHCMR} min varies 1:1 with V_{EE} , V_{IHCMR} max varies 1:1 with GND.

TTL OUTPUT DC CHARACTERISTICS V_{CC} = 4.5 V to 5.5 V; T_A = -40°C to +85°C

Symbol	Characteristic	Condition	Min	Тур	Max	Unit
V _{OH}	Output HIGH Voltage	$I_{OH} = -3.0 \text{ mA}$	2.4			V
V _{OL}	Output LOW Voltage	I _{OL} = 24 mA			0.5	V
I _{CCH}	Power Supply Current			11	16	mA
I _{CCL}	Power Supply Current			13	18	mA
I _{EE}	Negative Power Supply Current			15	21	mA
I _{OS}	Output Short Circuit Current		-150		-60	mA

AC CHARACTERISTICS V_{CC} = 5.0 V; V_{EE} = -5.0 V; GND= 0 V (Note 6 and Note 7)

			-40°C			25°C			85°C		
Symbol	Characteristic	Min	Тур	Max	Min	Тур	Max	Min	Тур	Max	Unit
f _{max}	Maximum Toggle Frequency		100			100			100		MHz
t _{PLH}	Propagation Delay @ 1.5 V C _L = 20 pF	1.7		3.6	1.7		3.6	1.7		3.6	ns
t _{PHL}	Propagation Delay @ 1.5 V C _L = 20 pF	2.6		4.1	2.6		4.1	2.6		4.1	ns
t _{JITTER}	Cycle-to-Cycle Jitter		TBD			TBD			TBD		ps
t _r t _f						1.9 2.3					ns
V_{PP}	Input Swing (Note 8)	200		1000	200		1000	200		1000	mV

^{6.} V_{CC} can vary ± 0.25 V.
V_{EE} can vary +0.06 V / −0.5 V for 10ELT; V_{EE} can vary +0.8 V / −0.5 V for 100ELT.
7. All loading with 500 ohms to GND, CL = 20 pF.
8. V_{PP}(min) is the minimum input swing for which AC parameters are guaranteed. The device has a DC gain of ≈40.

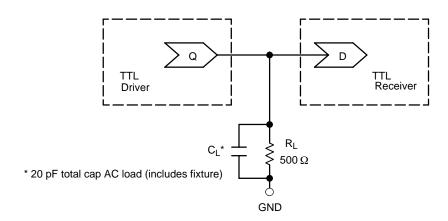


Figure 2. TTL Output Loading Used for Device Evaluation

Resource Reference of Application Notes

AN1404 – ECLinPS Circuit Performance at Non–Standard V_{IH} Levels

AN1405 – ECL Clock Distribution Techniques

AN1406 – Designing with PECL (ECL at +5.0 V)

AN1503 - ECLinPS I/O SPICE Modeling Kit

AN1504 – Metastability and the ECLinPS Family

AN1560 – Low Voltage ECLinPS SPICE Modeling Kit

AN1568 – Interfacing Between LVDS and ECL

AN1596 – ECLinPS Lite Translator ELT Family SPICE I/O Model Kit

AN1650 – Using Wire-OR Ties in ECLinPS Designs

AN1672 – The ECL Translator Guide

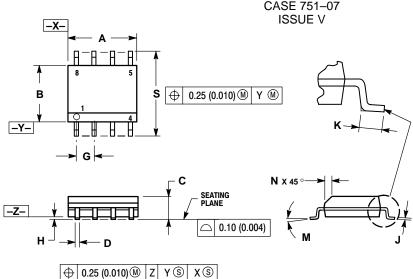
AND8001 - Odd Number Counters Design

AND8002 – Marking and Date Codes

AND8020 - Termination of ECL Logic Devices

PACKAGE DIMENSIONS

SO-8 **D SUFFIX** PLASTIC SOIC PACKAGE CASE 751-07

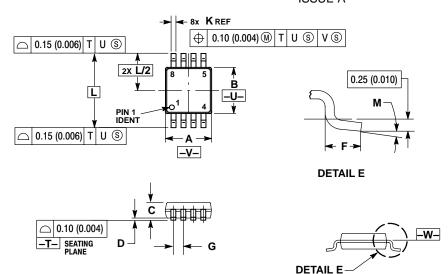


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE
- 4. MAXIMUM MOLD PHOTHUSION 0.15 (0.006) PER SIDE.
 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	7 BSC	0.050 BSC		
Н	0.10	0.25	0.004	0.010	
_	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
M	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

PACKAGE DIMENSIONS

TSSOP-8 **DT SUFFIX** PLASTIC TSSOP PACKAGE CASE 948R-02 **ISSUE A**



NOTES:

- OTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH. PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.

 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

 5. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
- REFERENCE ONLY.

 6. DIMENSION A AND B ARE TO BE
 DETERMINED AT DATUM PLANE -W-.

	MILLIN	IETERS	INC	HES
DIM	MIN	MAX	MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
C	0.80	1.10	0.031	0.043
D	0.05	0.15	0.002	0.006
F	0.40	0.70	0.016	0.028
G	0.65	BSC	0.026	BSC
K	0.25	0.40	0.010	0.016
L	4.90 BSC		0.193	BSC
М	0.0	6 °	0 °	6°



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